

# MGA-637P8

## High Linearity Low Noise Amplifier



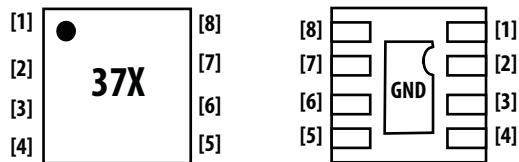
### Data Sheet

#### Description

Avago Technologies' MGA-637P8 is an economical, easy-to-use GaAs MMIC Low Noise Amplifier (LNA). This LNA has low noise and high linearity achieved through the use of Avago Technologies' proprietary 0.25  $\mu\text{m}$  GaAs Enhancement-mode pHEMT process. It is housed in the miniature 2.0 x 2.0 x 0.75 mm<sup>3</sup> 8-pin Dual-Flat-Non-Lead (DFN) package. The device is designed for optimum use from 1.5 GHz up to 2.5 GHz. The compact footprint and low profile coupled with low noise, high gain and high linearity make this an ideal choice as a low noise amplifier for cellular infrastructure applications such as LTE, GSM, CDMA, W-CDMA, CDMA2000 & TD-SCDMA. For optimum performance at lower frequency from 450 MHz up to 1.5 GHz, MGA-636P8 is recommended. For optimum performance at higher frequency from 2.5 GHz up to 4 GHz, MGA-638P8 is recommended. All these 3 products, MGA-636P8, MGA-637P8 and MGA-638P8 share the same package and pinout configuration.

#### Pin Configuration and Package Marking

2.0 x 2.0 x 0.75 mm<sup>3</sup> 8-lead DFN



TOP VIEW

- Pin 1 – Not Used
- Pin 2 – RFin
- Pin 3 – Vbias2
- Pin 4 – Not Used
- Center paddle – GND

BOTTOM VIEW

- Pin 5 – Vbias1
- Pin 6 – PwrDwn
- Pin 7 – RFout
- Pin 8 – Not Used

Note:  
 Package marking provides orientation and identification  
 "37" = Product Code  
 "X" = Month Code

It is recommended to ground Pin1, 4 and 8 which are Not Used.

#### Features

- High linearity performance.
- Low Noise Figure.
- GaAs E-pHEMT Technology<sup>[1]</sup>.
- Low cost small package size.
- Integrated with active bias and option to access FET gate.
- Integrated power down control pin.

#### Specifications

1.7 GHz; 4.8 V, 75 mA


- 17.3 dB Gain
- 0.52 dB Noise Figure
- 11 dB Input Return Loss
- +22.5 dBm Input IP3
- +21.9 dBm Output Power at 1 dB gain compression

#### Applications

- Cellular infrastructure applications such as LTE, GSM, CDMA, W-CDMA, CDMA2000 & TD-SCDMA.
- Other low noise applications.

Note:

1. Enhancement mode technology employs positive Vgs, thereby eliminating the need of negative gate voltage associated with conventional depletion mode devices.



**Attention: Observe precautions for handling electrostatic sensitive devices.**  
 ESD Machine Model = 80 V  
 ESD Human Body Model = 350 V  
 Refer to Avago Application Note A004R: Electrostatic Discharge, Damage and Control.



## Electrical Specifications<sup>[1, 4]</sup>

$T_A = 25^\circ\text{C}$ ,  $V_{dd} = V_{bias1} = 4.8\text{V}$ , RF measurement at 1.7 GHz, measured on demo board in Figure 5 with component listed in Table1.

Symbol	Parameter and Test Condition	Units	Min.	Typ.	Max.
I <sub>dd</sub>	Bias Current	mA	59	75	101
I <sub>PwrDwn</sub>	Current at V <sub>PwrDwn</sub> pin when V <sub>PwrDwn</sub> = 3.3 V (Power Down mode)	mA	–	0.15	–
Gain	Gain	dB	16	17.3	19
NF <sup>[2]</sup>	Noise Figure	dB	–	0.52	0.75
IIP3 <sup>[3]</sup>	Input Third Order Intercept Point	dBm	21	22.5	–
OP1dB	Output Power at 1dB Gain Compression	dBm	–	21.9	–
IRL	Input Return Loss, 50 Ω source	dB	–	13	–
ORL	Output Return Loss, 50 Ω load	dB	–	15.8	–

Notes:

1. Measurements at 1.7 GHz obtained using demo board described in Figure 5.
2. For NF data, board losses of the input have not been de-embedded.
3. IIP3 test condition:  $F_{RF1} = 1.700\text{ GHz}$ ,  $F_{RF2} = 1.701\text{ GHz}$  with input power of -10 dBm per tone.
4. Use proper bias, heatsink and derating to ensure maximum channel temperature is not exceeded. See absolute maximum ratings and application note for more details.

## Product Consistency Distribution Charts<sup>[1, 2]</sup>

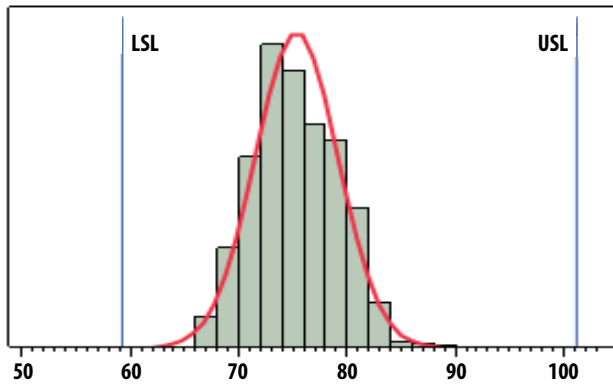


Figure 1. I<sub>dd</sub>, LSL = 59 mA, nominal = 75 mA, USL = 101 mA

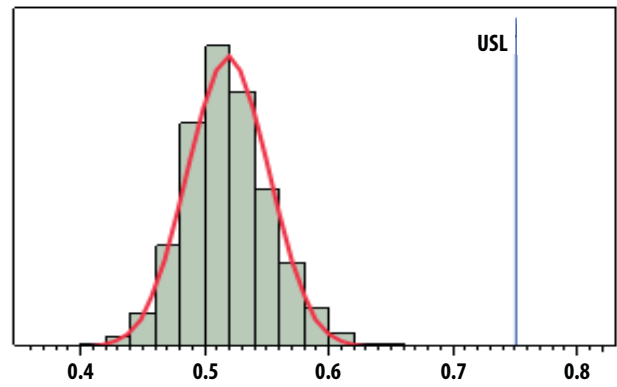


Figure 2. NF, nominal = 0.52 dB, USL = 0.75 dB

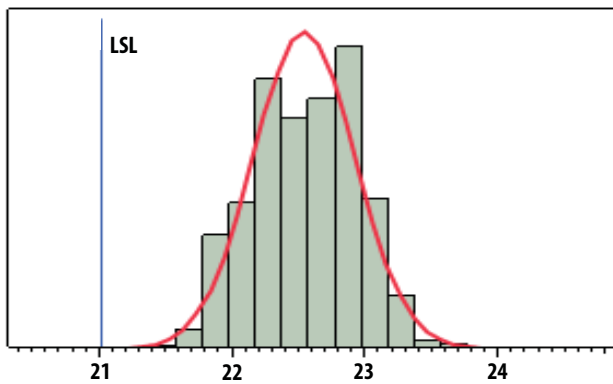


Figure 3. IIP3, LSL = 21 dBm, nominal = 22.5 dBm

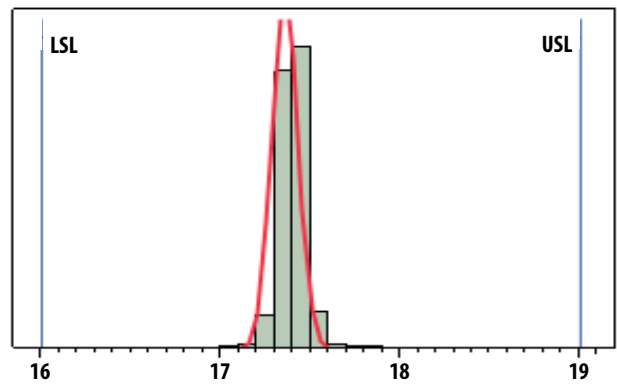


Figure 4. Gain, LSL = 16 dB, nominal = 17.3 dB, USL = 19 dB

Notes:

1. Distribution data sample size is 500 samples taken from 3 different wafer lots. Future wafers allocated to this product may have nominal values anywhere between the upper and lower limits.
2. Circuit trace losses have not been de-embedded from measurements above.

## Demo Board Layout

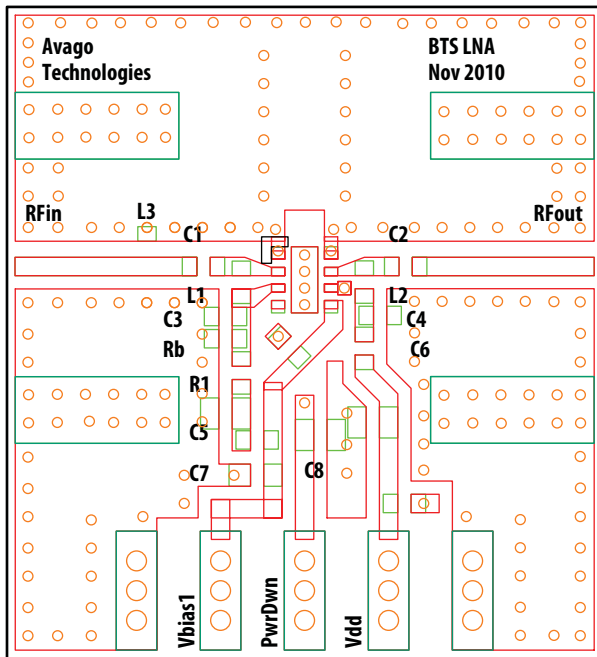
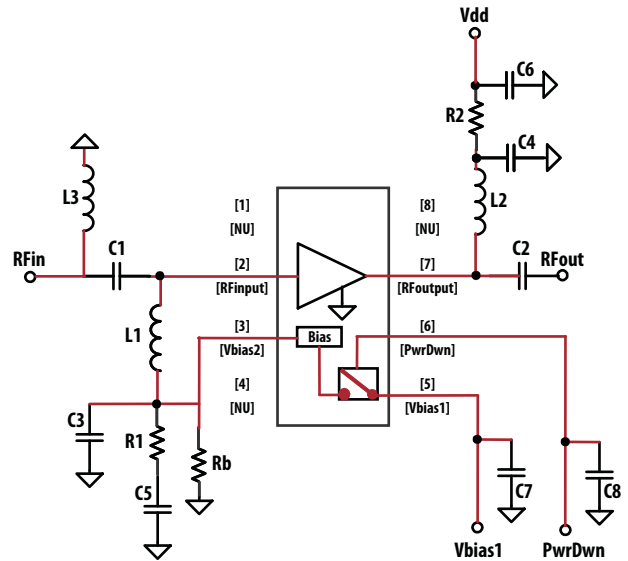


Figure 5. Demo Board Layout Diagram

- Recommended PCB material is 10 mils Rogers RO4350.
- Suggested component values may vary according to layout and PCB material.

## Demo Board Schematic



Truth Table

	V <sub>PwrDwn</sub> (V)
LNA Mode	0 or open
Power Down Mode	3.3

Figure 6. Demo Board Schematic Diagram

Notes:

- The schematic is shown with the assumption that similar PCB is used for all MGA-636P8, MGA-637P8 and MGA-638P8.
- Detail of the components needed for this product is shown in Table 1.

Table 1. Component list for 1.7 GHz matching

Part	Size	Value	Detail Part Number
C1	0402	100 pF (Murata)	GRM1555C1H101JD01D
C2	0402	150 pF (Murata)	GRM1555C1H151JD01D
C5, C6, C7, C8	0603	4.7 $\mu$ F (Murata)	GRM188R60J475KE19D
C3, C4	0402	Not Used	
L1, L2	0402	8.2 nH (Toko)	LLP1005-FH8N2C
L3	0402	Not Used	
Rb	0402	750 ohm (Rohm)	MCR004YZPJ751
R1, R2	0402	0 ohm (Rohm)	MCR01MZPJ000

Notes:

- C1, C2 are DC blocking capacitors
- L1 input match for NF
- L2 output match for IP3
- C5, C6, C7, C8 are bypass capacitors
- Rb is the biasing resistor

## Typical Performance

RF performance at  $T_A = 25^\circ\text{C}$ ,  $V_{dd} = 4.8\text{ V}$ ,  $I_{dd} = 75\text{ mA}$ , measured using 50 ohm input and output board unless stated otherwise. IIP3 test condition:  $F_{RF1}-F_{RF2} = 1\text{ MHz}$  with input power of  $-10\text{ dBm}$  per tone.

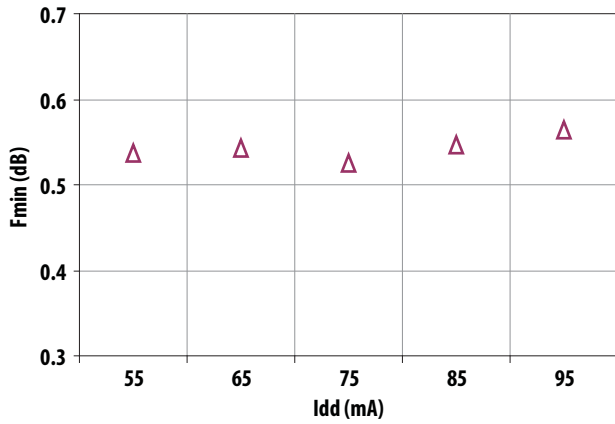


Figure 7. Fmin vs Idd at 4.8 V at 1.7 GHz

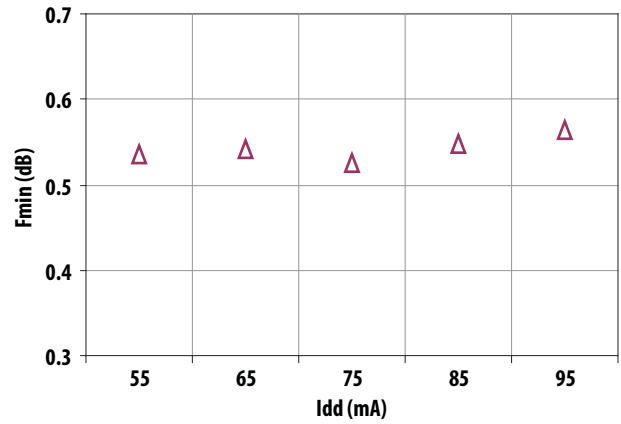


Figure 8. Fmin vs Idd at 4.8 V at 1.9 GHz

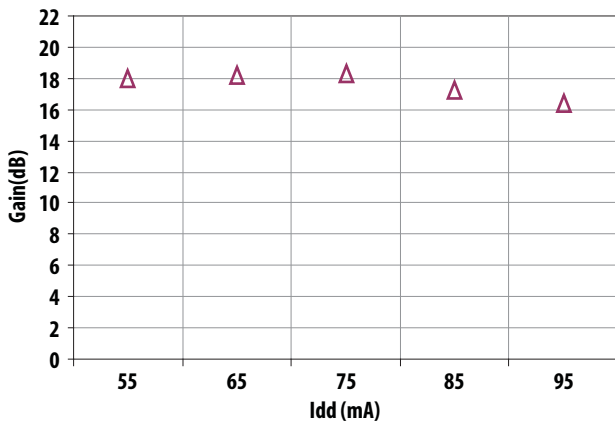


Figure 9. Gain vs Idd at 4.8 V Tuned for Optimum IIP3 and Fmin at 1.7 GHz

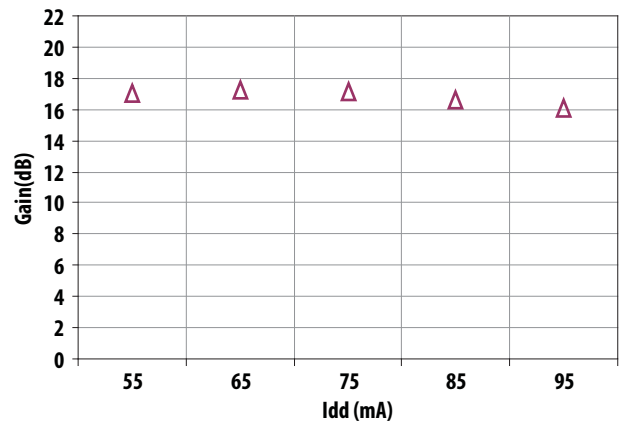


Figure 10. Gain vs Idd at 4.8 V Tuned for Optimum IIP3 and Fmin at 1.9 GHz

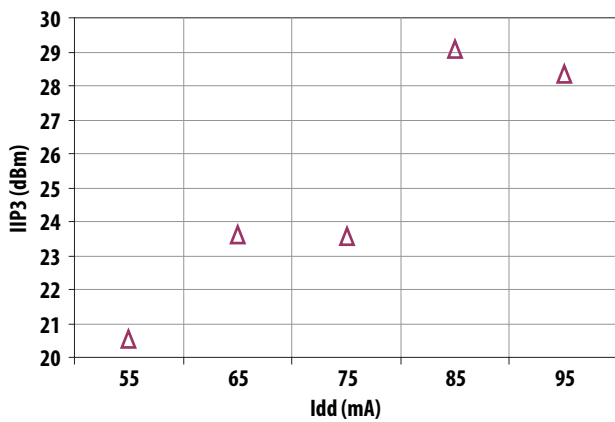


Figure 11. IIP3 vs Idd at 4.8 V Tuned for Optimum IIP3 and Fmin at 1.7 GHz

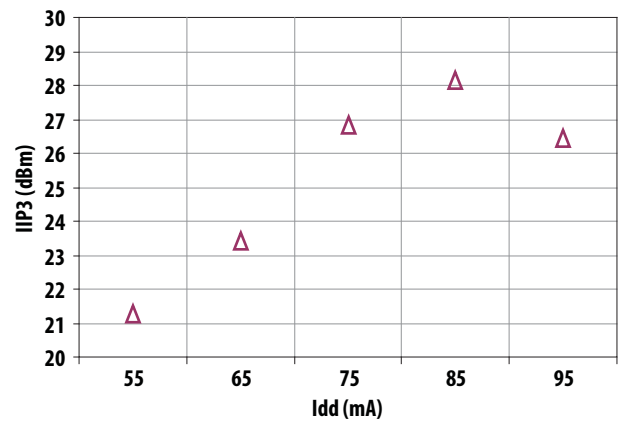


Figure 12. IIP3 vs Idd at 4.8 V Tuned for Optimum IIP3 and Fmin at 1.9 GHz

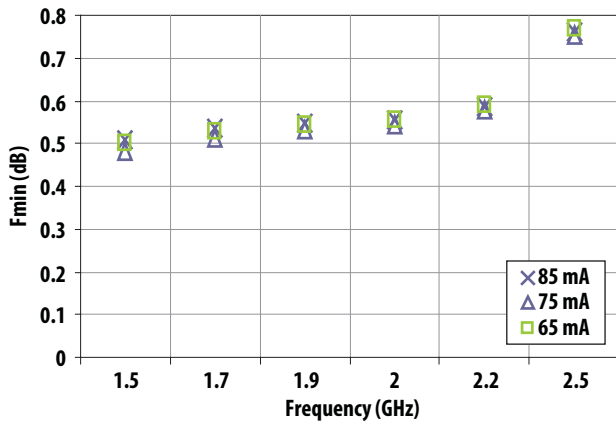


Figure 13. Fmin vs Frequency and Idd at 4.8 V

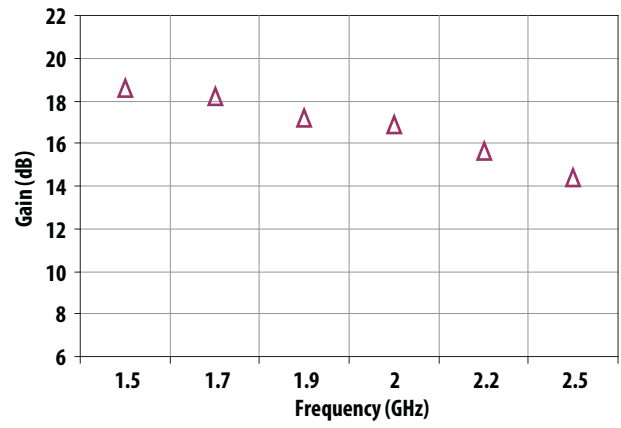


Figure 14. Gain vs Frequency for Optimum IIP3 and Fmin at 4.8 V 75 mA

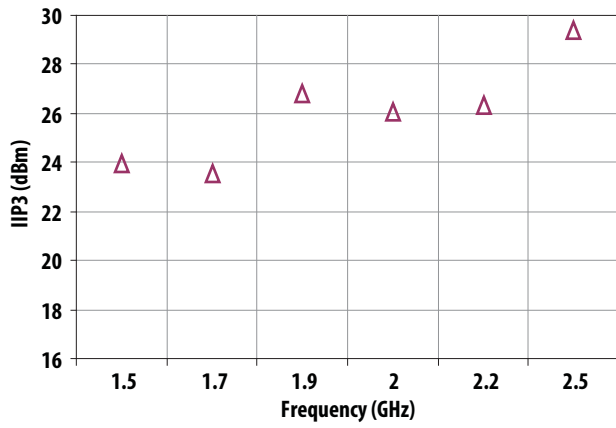
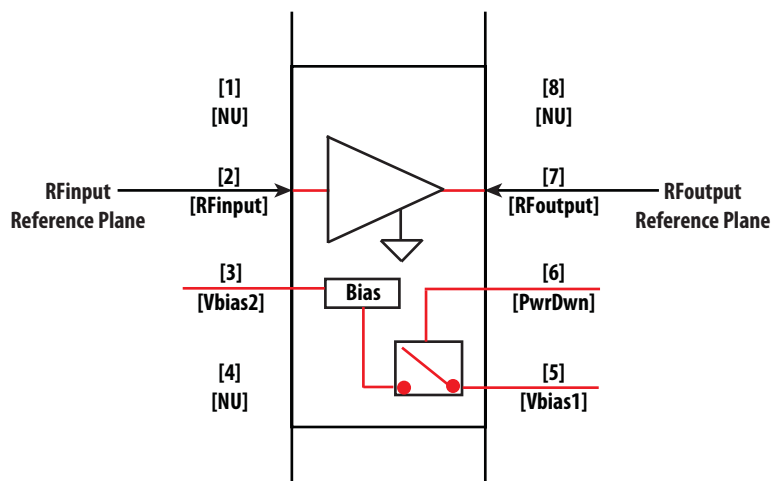


Figure 15. IIP3 vs Frequency for Optimum IIP3 and Fmin at 4.8 V 75 mA

Below is the table showing the MGA-637P8 Reflection Coefficient Parameters tuned for Maximum IIP3, Vdd = 4.8 V, Idd = 75 mA.

Frequency (GHz)	Gamma Load position		IIP3 (dBm)
	Magnitude	Angle	
1.5	0.27	99.9	25.3
1.7	0.27	100	26
1.9	0.27	119.9	27.2
2.0	0.27	120	28
2.2	0.36	129.7	28.7
2.5	0.36	143.9	30.2



**Figure 16. RFinput and RFoutput Reference Plane**

Notes:

1. The Maximum IIP3 values are calculated based on Load pull measurements on approximately 100 different impedances using Focus Load pull test system.
2. Measurements are conducted on 0.010 inch thick ROGER 4350. The input reference plane is at the end of the RFin pin and the output reference plane is at the end of the RFout pin as shown in Figure 16.

## Typical Performance

RF performance at  $T_A = 25^\circ\text{C}$ ,  $V_{dd} = V_{bias1} = 4.8\text{ V}$ ,  $I_{dd} = 75\text{ mA}$ , LNA mode, measured on demo board in Figure 5. Signal = CW unless stated otherwise. Application Test Circuit is shown in Figure 6 and Table 1. IIP3 test condition:  $F_{RF1} - F_{RF2} = 1\text{ MHz}$  with input power of  $-10\text{ dBm}$  per tone.

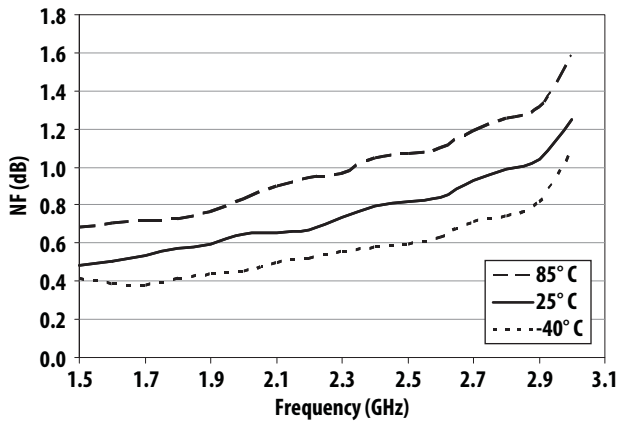


Figure 17. NF vs Frequency vs Temperature

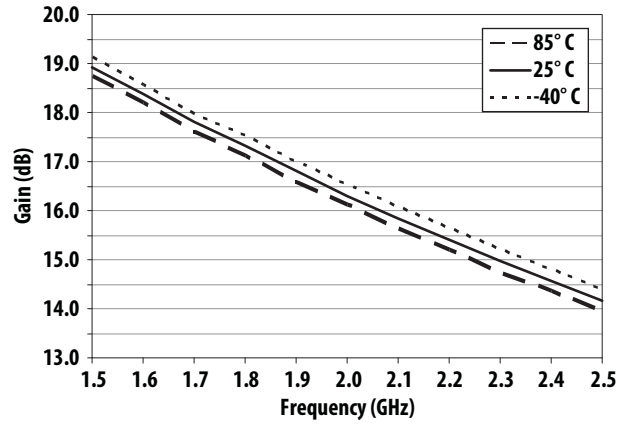


Figure 18. Gain vs Frequency vs Temperature

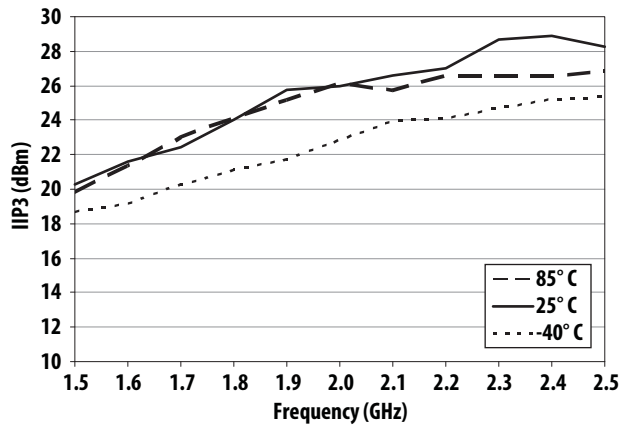


Figure 19. IIP3 vs Frequency vs Temperature

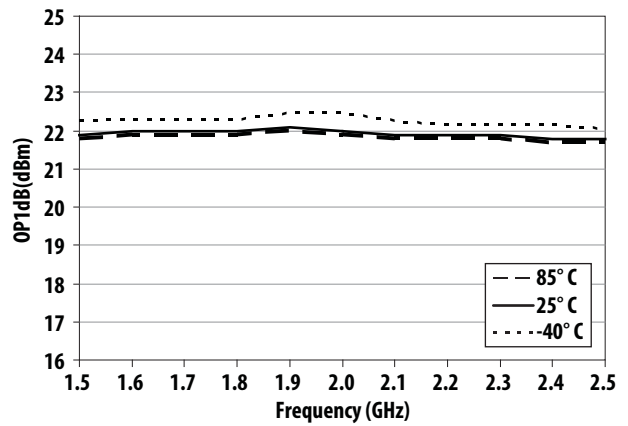


Figure 20. OP1dB vs Frequency vs Temperature



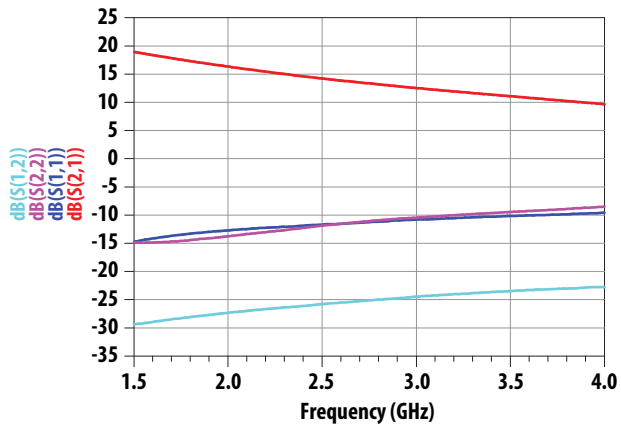


Figure 21. Input Return Loss, Output Return Loss, Gain, Reverse Isolation vs Frequency

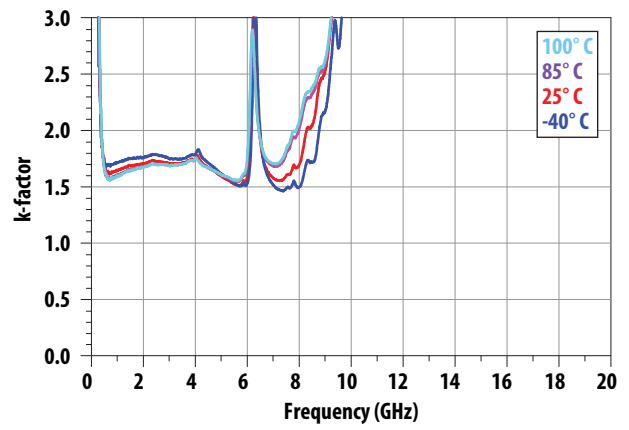


Figure 22. k-factor vs Frequency vs Temperature

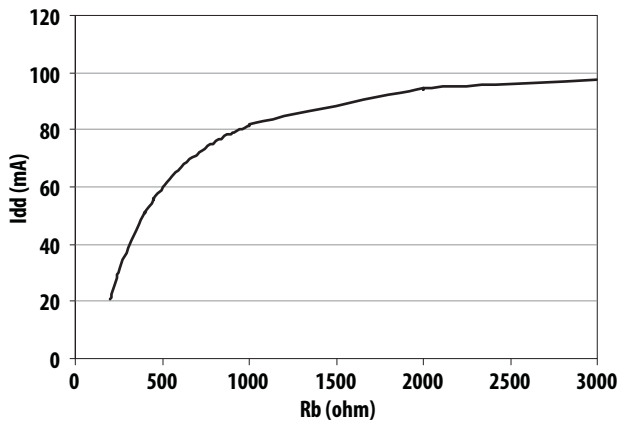


Figure 23. Idd vs Rb

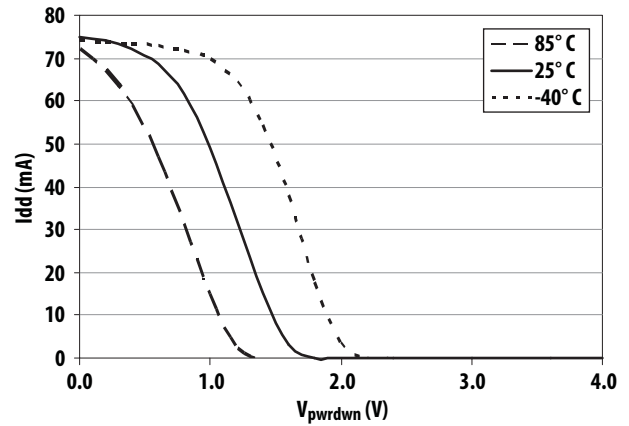


Figure 24. Idd vs  $V_{pwrdown}$

## Typical Scattering Parameters, Vdd = 4.8 V, Idd = 75 mA

### LNA SPAR (100 MHz – 20 GHz)

Freq (GHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
0.1	-0.329	-22.999	33.852	148.157	-48.343	89.846	-3.56	-28.96
0.5	-5.991	-75.335	26.793	101.778	-37.553	68.482	-9.343	-42.722
0.7	-7.885	-88.201	24.381	90.298	-35.261	67.398	-10.033	-45.831
0.9	-9.209	-98.163	22.444	81.171	-33.47	66.028	-10.32	-49.973
1.0	-9.702	-101.134	21.599	77.242	-32.687	65.327	-10.275	-51.379
1.5	-11.151	-116.34	18.278	59.797	-29.648	61.018	-10.152	-63.539
1.7	-11.276	-122.907	17.226	53.244	-28.7	58.653	-10.128	-70.304
1.9	-11.28	-128.572	16.273	46.935	-27.88	56.39	-10.016	-77.005
2.0	-11.229	-131.135	15.822	43.855	-27.484	55.174	-9.922	-80.341
2.5	-10.769	-141.135	13.846	29.093	-25.85	49.214	-9.277	-96.744
3	-10.175	-148.444	12.169	15.07	-24.576	43.459	-8.47	-110.824
3.5	-9.562	-154.544	10.721	1.694	-23.511	37.989	-7.648	-122.637
4	-8.981	-159.914	9.465	-10.717	-22.487	33.134	-6.837	-133.403
4.5	-8.422	-166.312	8.43	-23.396	-21.619	27.803	-6.326	-143.965
5	-7.886	-174.086	7.427	-36.283	-20.85	22.415	-5.792	-154.912
5.5	-7.37	176.754	6.479	-49.17	-20.128	17.017	-5.329	-166.087
6	-6.889	166.657	5.61	-62.254	-19.395	11.192	-4.972	-177.579
7	-5.56	147.502	3.617	-88.076	-18.321	-1.075	-4.149	160.414
8	-4.329	135.731	1.376	-110.949	-17.688	-11.478	-3.34	143.283
9	-3.729	126.937	-0.866	-131.216	-16.886	-19.591	-3.081	130.105
10	-3.502	113.258	-2.61	-152.59	-15.681	-30.852	-2.366	113.034
11	-3.208	97.368	-4.934	-177.297	-14.905	-46.367	-2.241	88.557
12	-3.079	83.346	-7.811	158.326	-14.427	-62.459	-1.971	64.563
13	-3.133	68.38	-11.487	136.173	-14.497	-77.811	-1.813	46.387
14	-3.002	54.811	-15.566	121.173	-14.455	-87.355	-2.709	36.535
15	-2.865	48.736	-18.501	113.896	-13.135	-90.676	-3.722	50.249
16	-3.111	45.795	-24.606	83.96	-12.225	-107.4	-2.615	28.754
17	-3.355	38.022	-39.471	-2.18	-12.552	-124.888	-2.917	0.394
18	-3.245	27.651	-28.848	-107.903	-12.801	-138.791	-3.083	-12.005
19	-3.219	14.019	-24.346	-130.67	-13.289	-153.698	-2.647	-13.451
20	-3.289	-1.387	-21.594	-148.155	-13.144	-167.611	-2.637	-8.352

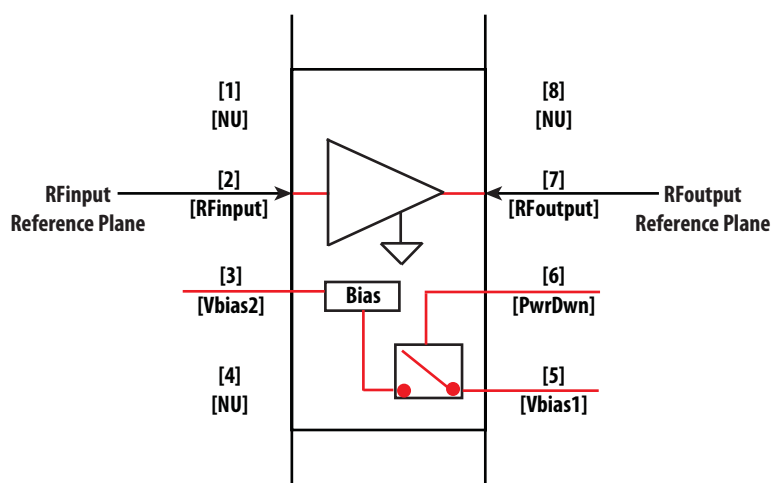


Figure 25. RFinput and RFoutput Reference Plane

### Typical Noise Parameters, $V_{dd} = 4.8\text{ V}$ , $I_{dd} = 75\text{ mA}$

Freq GHz	Fmin dB	$\Gamma_{opt}$ Mag.	$\Gamma_{opt}$ Ang.	$R_n/50$
1.5	0.48	0.129	142.7	0.041
1.7	0.51	0.151	151.5	0.041
1.9	0.53	0.174	160.3	0.038
2	0.54	0.185	164.7	0.037
2.2	0.58	0.207	173.5	0.037
2.5	0.75	0.241	186.6	0.048

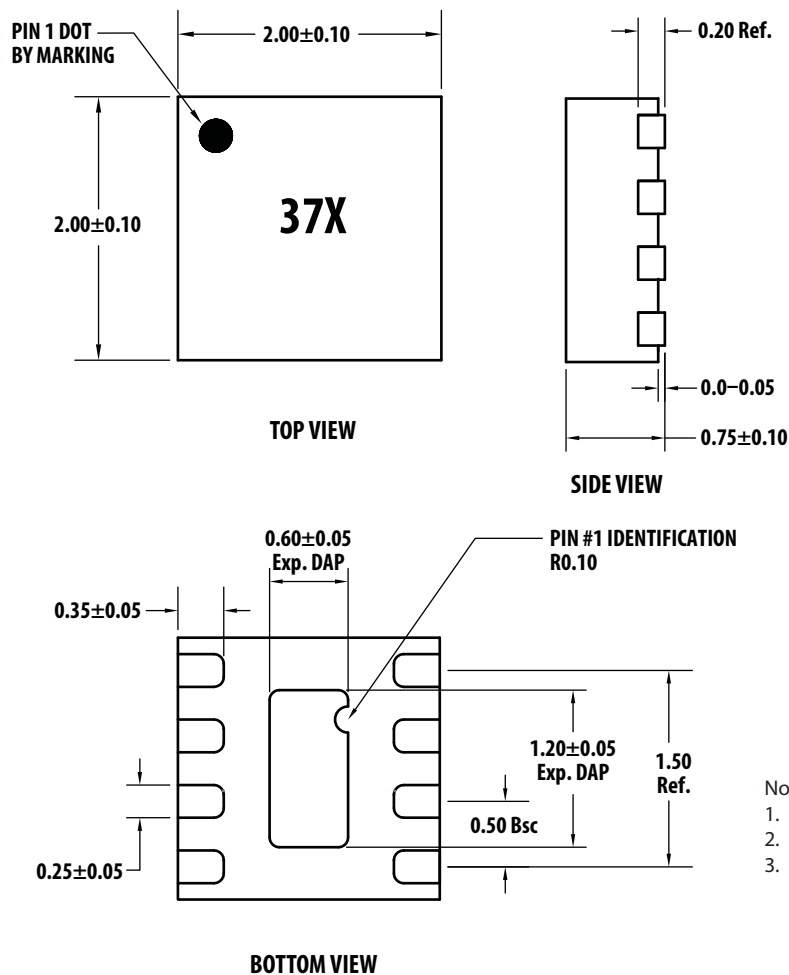
#### Notes:

1. The Fmin values are based on noise figure measurements at 100 different impedances using Focus source pull test system. From these measurements a true Fmin is calculated.
2. Scattering and noise parameters are measured on coplanar waveguide made on 0.010 inch thick ROGER 4350. The input reference plane is at the end of the RFinpin and the output reference plane is at the end of the RFoutpin as shown in Figure 25.

### Part Number Ordering Information

Part Number	No. of Devices	Container
MGA-637P8-BLKG	100	Antistatic Bag
MGA-637P8-TR1G	3000	7 inch Reel

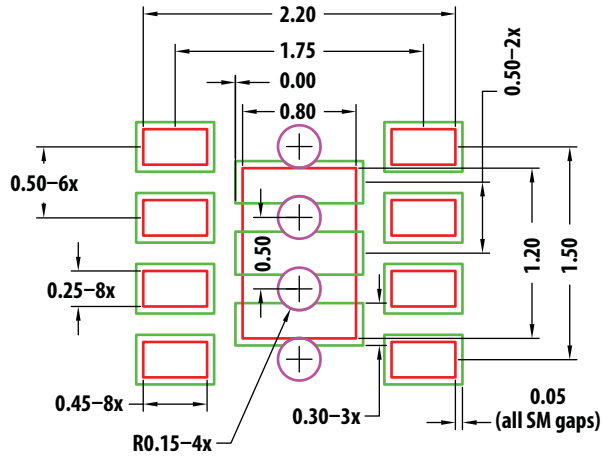
### DFN2X2 Package Dimensions



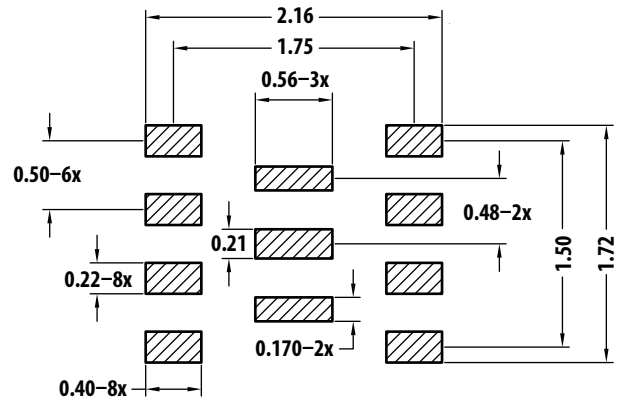
#### Notes:

1. All dimensions are in millimeters.
2. Dimensions are inclusive of plating.
3. Dimensions are exclusive of mold ash and metal burr.

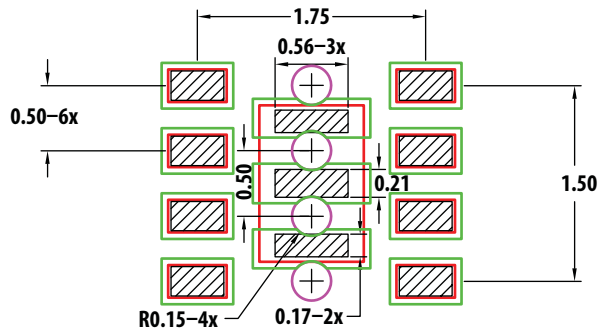
## Recommended PCB Land Pattern and Stencil Design



PCB Land Pattern



Stencil Design



Combines PCB & Stencil Design

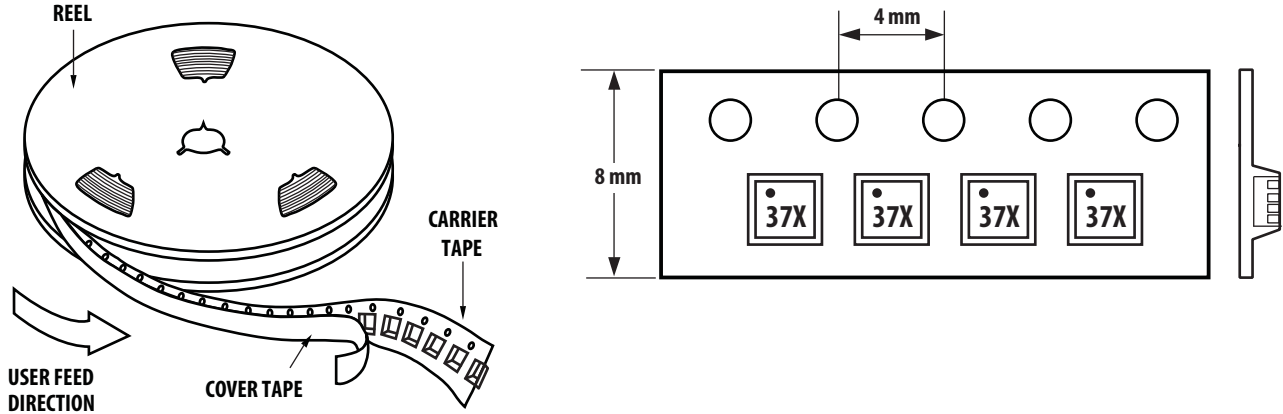


All Dimension are in millimeters

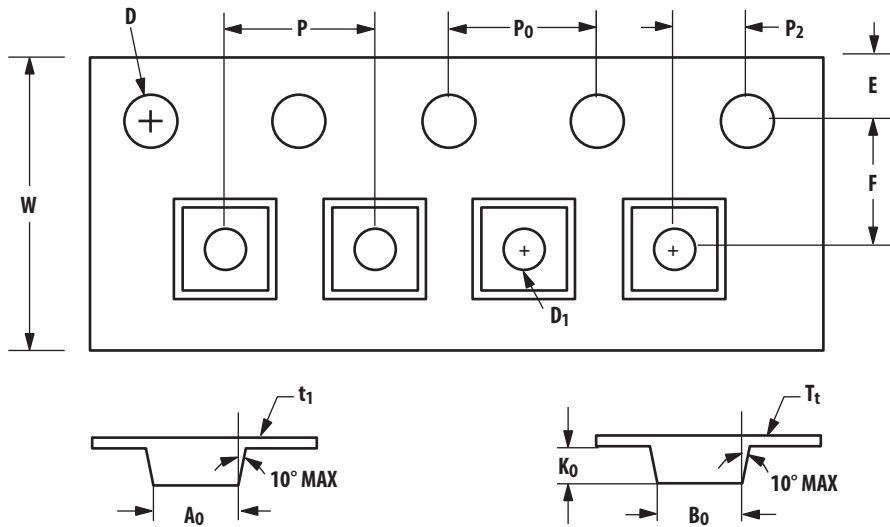
Notes:

1. Stencil thickness is 0.1 mm (4 mils).
2. All dimensions are in mm unless otherwise specified.

## Device Orientation

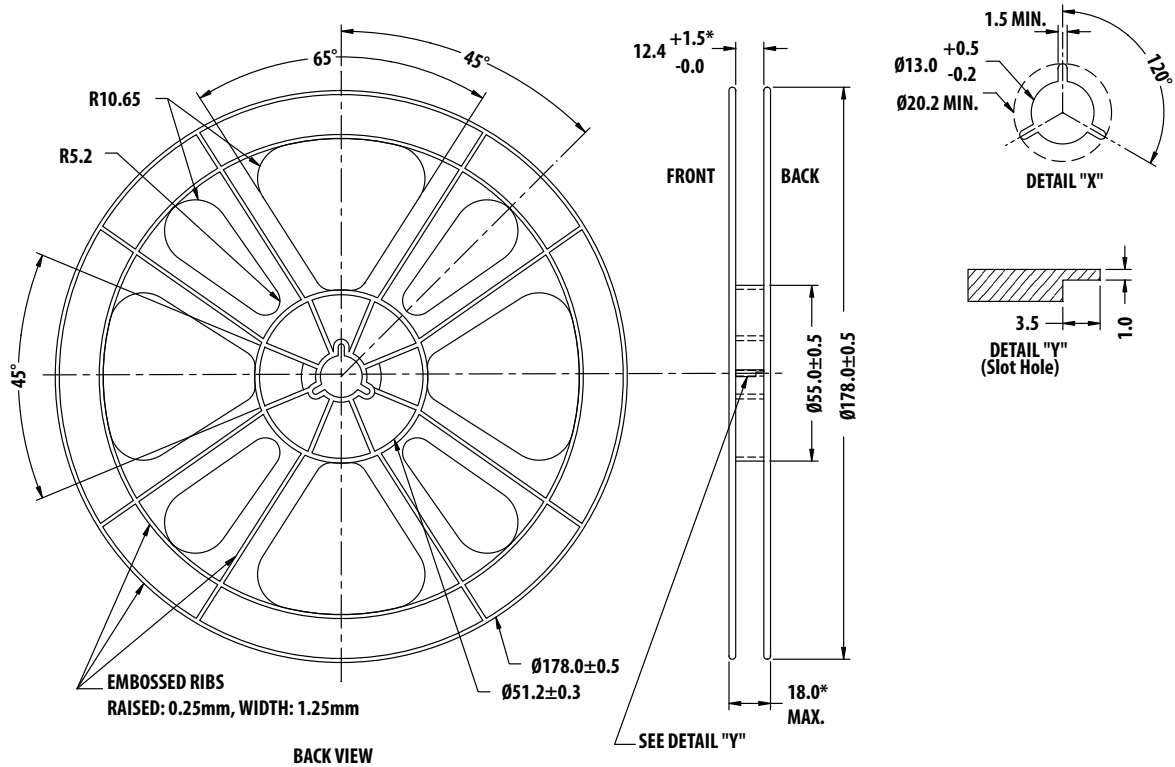
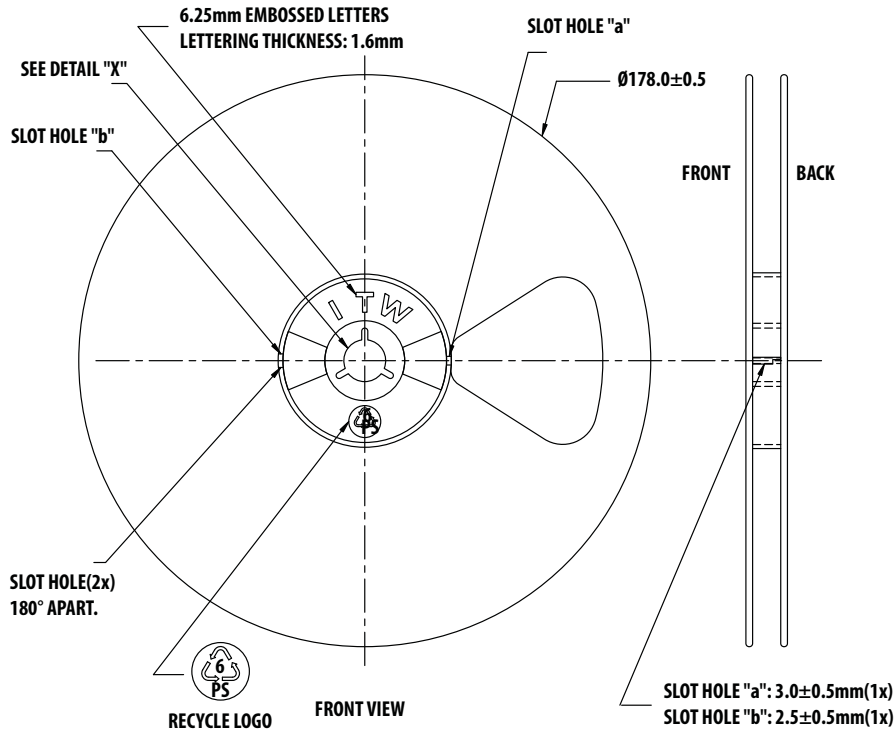


## Tape Dimensions



	DESCRIPTION	SYMBOL	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH	$A_0$	$2.30 \pm 0.05$	$0.091 \pm 0.004$
	WIDTH	$B_0$	$2.30 \pm 0.05$	$0.091 \pm 0.004$
	DEPTH	$K_0$	$1.00 \pm 0.05$	$0.039 \pm 0.002$
	PITCH	$P$	$4.00 \pm 0.10$	$0.157 \pm 0.004$
	BOTTOM HOLE DIAMETER	$D_1$	$1.00 + 0.25$	$0.039 + 0.002$
	PERFORATION	DIAMETER	$D$	$1.50 \pm 0.10$
PITCH		$P_0$	$4.00 \pm 0.10$	$0.157 \pm 0.004$
POSITION		$E$	$1.75 \pm 0.10$	$0.069 \pm 0.004$
		$F$	$3.50 \pm 0.05$	$0.138 \pm 0.002$
CARRIER TAPE	WIDTH	$W$	$8.00 \pm 0.30$	$0.315 \pm 0.012$
	THICKNESS	$t_1$	$0.254 \pm 0.02$	$0.010 \pm 0.0008$
COVER TAPE	WIDTH	$C$	$5.4 \pm 0.10$	$0.205 \pm 0.004$
	TAPE THICKNESS	$T_t$	$0.062 \pm 0.001$	$0.0025 \pm 0.0004$
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	$F$	$3.50 \pm 0.05$	$0.138 \pm 0.002$
	CAVITY TO PERFORATION (LENGTH DIRECTION)	$P_2$	$2.00 \pm 0.05$	$0.079 \pm 0.002$

# Reel Dimensions – 7 inch



For product information and a complete list of distributors, please go to our web site: [www.avagotech.com](http://www.avagotech.com)

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